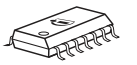
5-V Low Drop Fixed Voltage Regulator

TLE 4299

Features

- Output voltage 5 V ± 2%
- 150 mA Output current
- Extreme low current consumption typical 65 µA in ON state
- Inhibit function: Below 1 µA current consumption in off mode
- Early warning
- Reset output low down to V_Q = 1 V
- Adjustable reset threshold
- Overtemperature protection
- Reverse polarity proof
- Wide temperature range

P-DSO-8-3, -6, -7, -8, -9



P-DSO-14-3, -8, -9, -11, 14

Functional Description

The TLE 4299 is a monolithic voltage regulator with fixed 5-V output, supplying loads up to 150 mA. It is especially designed for applications that may not be powered down while the motor is off. It only needs a quiescent current of typical 65 µA. In addition the TLE 4299 GM includes an inhibit function. When the inhibit signal is removed, the device is switched off and the quiescent current is less than 1 µA. To achieve proper operation of the µ-controller, the device supplies a reset signal. The reset delay time is selected application-specific by an external delay capacitor. The reset threshold is adjustable. An early warning signal supervises the voltage at pin SI. The TLE 4299 is pin-compatible to the TLE 4269 and functional similar with the additional inhibit function. The TLE 4299 is designed to supply microcontroller systems even under automotive environment conditions. Therefore it is protected against overload, short circuit and overtemperature.

Type	Ordering Code	Package
TLE 4299 G	Q67006-A9417	P-DSO-8-3
TLE 4299 GM	Q67006-A9441	P-DSO-14-8

Circuit Description

The TLE 4299 is a PNP based very low drop linear voltage regular. It regulates the output voltage to V_Q = 5 V for an input voltage range of 5.5 V ≤ V_I ≤ 45 V. The control circuit protects the device against potential caused by damages overcurrent and overtemperature.

The internal control circuit achieves a 5 V output voltage with a tolerance of ±2%.

The device includes a power on reset and an under voltage reset function with adjustable reset delay time and adjustable reset switching threshold as well as a sense control/early warning function. The device includes an inhibit function to disable it when the ECU is not used for example while the motor is off.

The reset logic compares the output voltage V_Q to an internal threshold. If the output voltage drops below this level, the external reset delay capacitor C_D is discharged. When V_D is lower than V_{LD}, the reset output RO is switched Low. If the output voltage drop is very short, the V_{LD} level is not reached and no reset-signal is asserted. This feature avoids resets at short negative spikes at the output voltage e.g. caused by load changes.

As soon as the output voltage is more positive than the reset threshold, the delay capacitor is charged with constant current. When the voltage reaches V_{UD} the reset output RO is set High again.

The reset threshold is either the internal defined V_{RT} voltage (typical 4.6 V) or can be lowered by a voltage level at the RADJ input down to 3.5 V. The reset delay time and the reset reaction time are defined by the external capacitor C_D. The reset function is active down to V_I = 1 V.

In addition to the normal reset function, the device gives an early warning. When the SI voltage drops below $V_{SI,low}$, the devices asserts the SI output Low to indicate the logic and the µ-processor that this voltage has dropped. The sense function uses a hysteresis: When the SI-voltage reaches the $V_{SI,high}$ level, SO is set high again. This feature can be used as early warning function to notice the µ-controller about a battery voltage drop and a possible reset in a short time. Of cause also any other voltage can be observed by this feature.

The user defines the threshold by the resistor-values R_{SI1} and R_{SI2}.

For the exact timing and calculation of the reset and sense timing and thresholds, please refer to the application section.

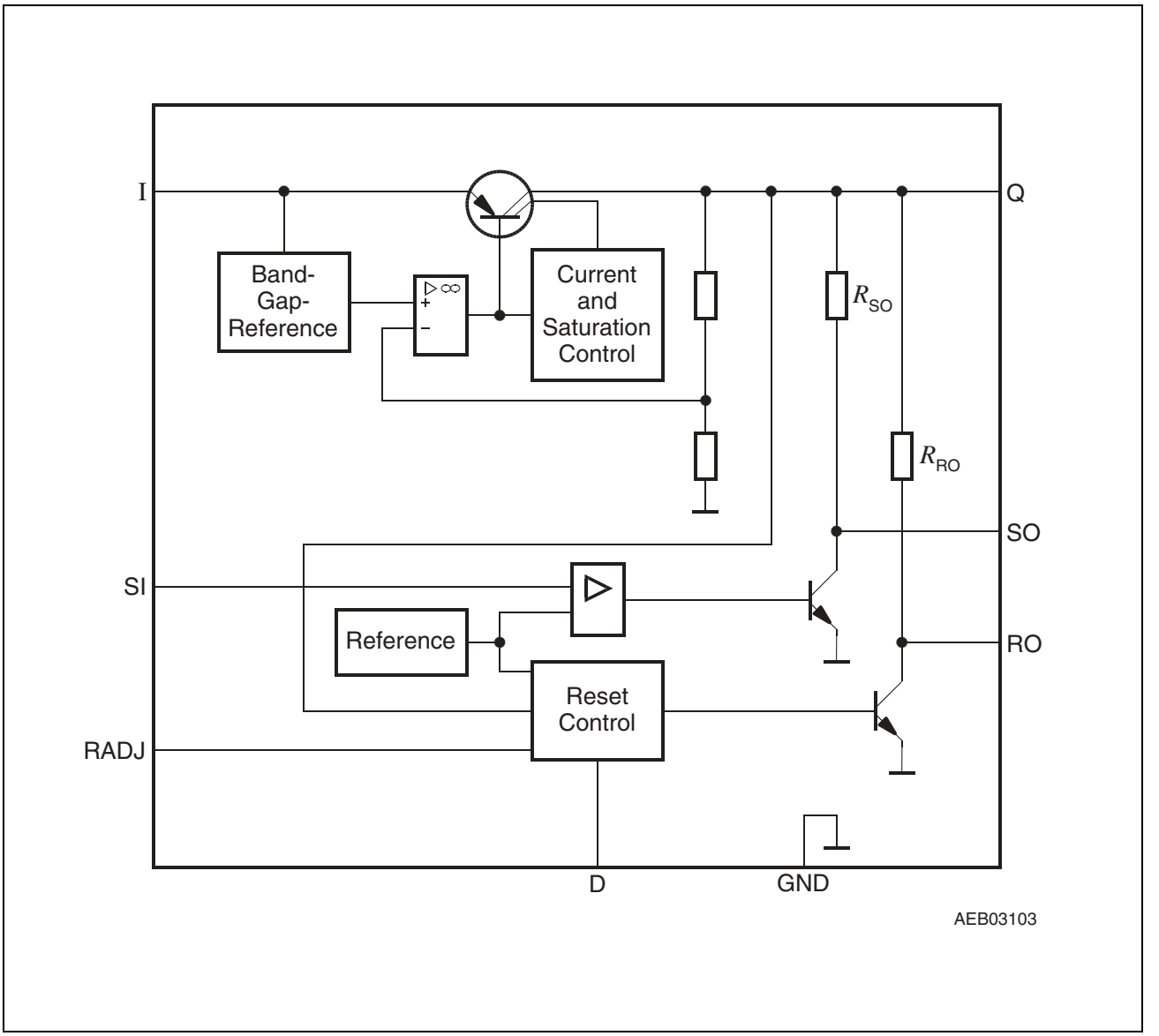


Figure 1 Block Diagram TLE 4299 G

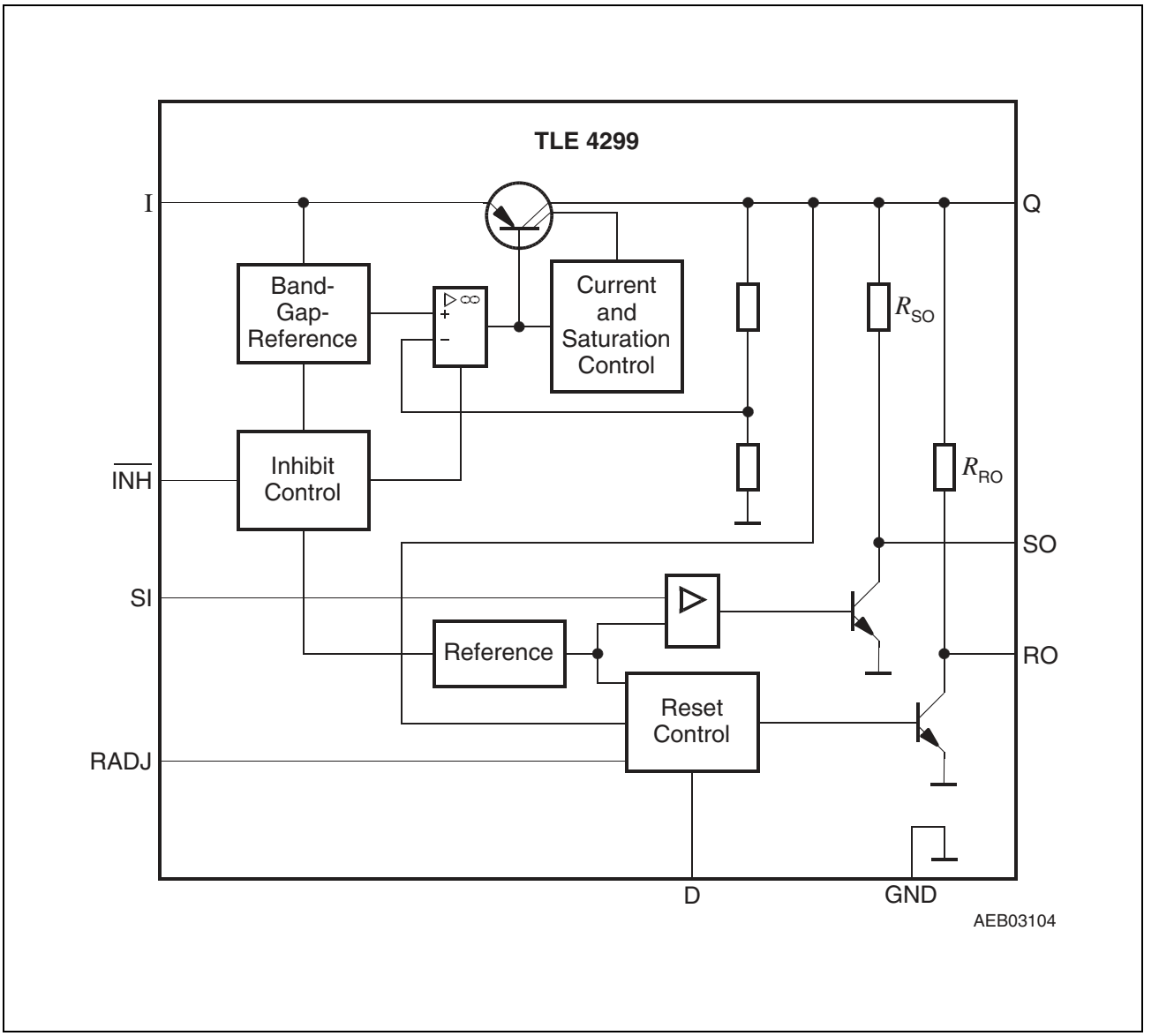


Figure 2 Block Diagram TLE 4299 GM

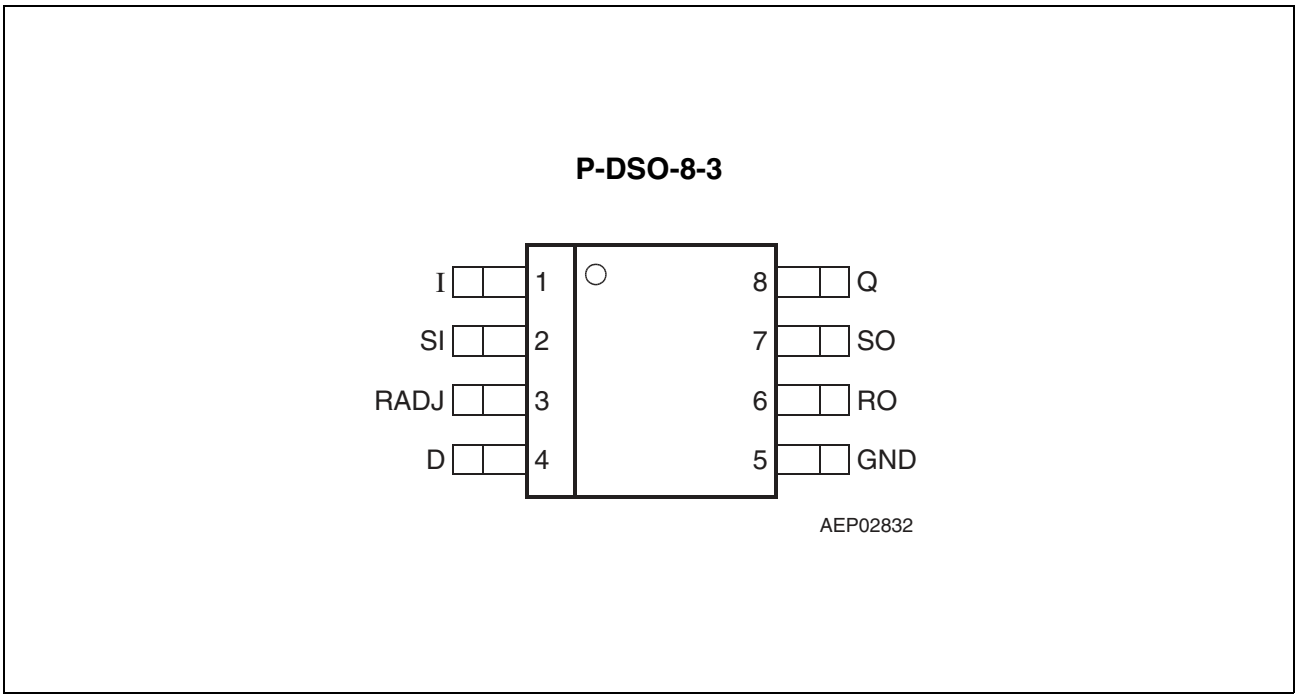


Figure 3 **Pin Configuration** (top view)

Table 1 **Pin Definitions and Functions (TLE 4299 G)**

Pin No.	Symbol	Function
1	I	**Input;** block directly to GND on the IC with a ceramic capacitor.
2	SI	**Sense Input;** if not needed connect to Q.
3	RADJ	**Reset Threshold;** if not needed connect to GND.
4	D	**Reset Delay;** to select delay time, connect to GND via external capacitor.
5	GND	**Ground**
6	RO	**Reset Output;** the open-collector output is internally linked to Q via a 20 kΩ pull-up resistor. Keep open, if the pin is not needed.
7	SO	**Sense Output;** the open-collector output is internally linked to the output via a 20 kΩ pull-up resistor. Keep open, if the pin is not needed.
8	Q	**5-V Output;** connect to GND with a 22 µF capacitor, ESR < 5 Ω.

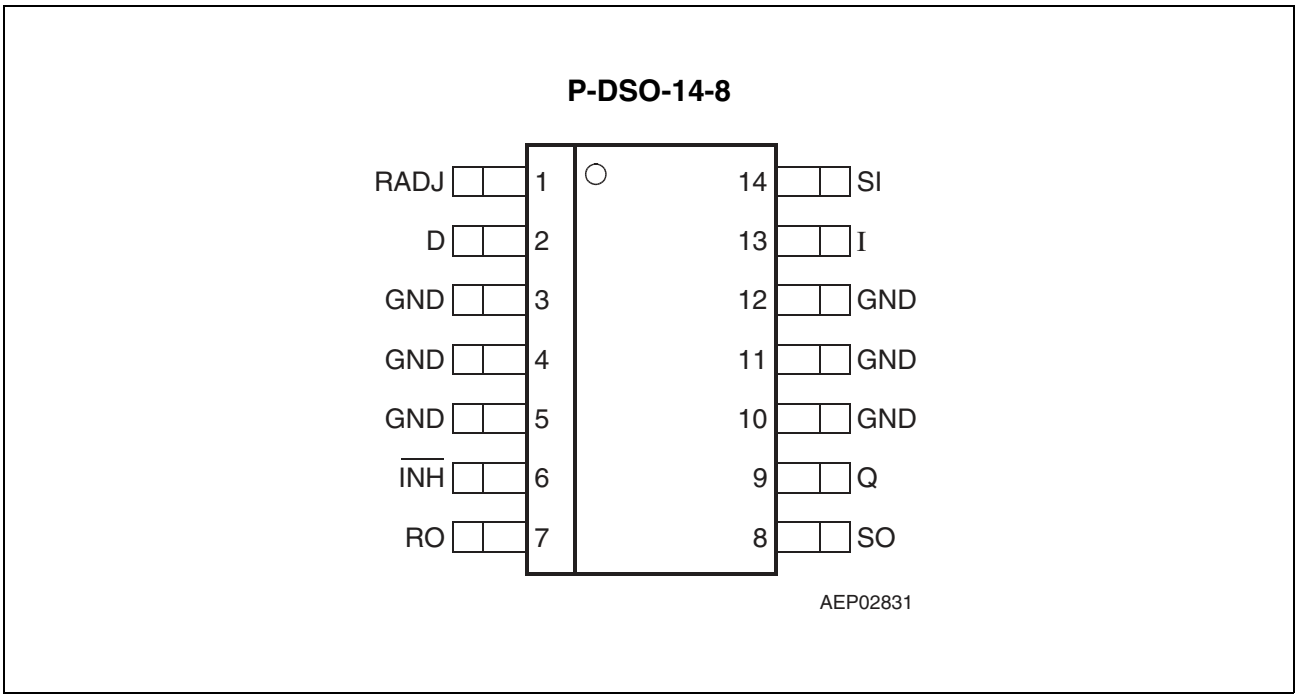


Figure 4 **Pin Configuration** (top view)

Table 2 **Pin Definitions and Functions (TLE 4299 GM)**

Pin No.	Symbol	Function
1	RADJ	**Reset Threshold;** if not needed connect to GND.
2	D	**Reset Delay;** connect to GND via external delay capacitor for setting delay time.
3, 4, 5	GND	**Ground**
6	$\overline{\text{INH}}$	**Inhibit;** If not needed connect to input pin I; a high signal switches the regulator ON.
7	RO	**Reset Output;** open-collector output, internally connected to Q via a pull-up resistor of 20 kΩ. Keep open, if the pin is not needed.
8	SO	**Sense Output;** open-collector output, internally connected to Q via a 20 kΩ pull-up resistor. Keep open, if the pin is not needed.
9	Q	**5-V Output;** connect to GND with a 22 µF capacitor, ESR < 5 Ω.
10, 11, 12	GND	**Ground**
13	I	**Input;** block to GND directly at the IC by a ceramic capacitor.
14	SI	**Sense Input;** if not needed connect to Q.

Table 3 Absolute Maximum Ratings

T_j = -40 to 150 °C

Parameter	Symbol	Limit Values		Unit	Notes
		Min.	Max.		
Input I					
Input voltage	V_I	-40	45	V	–
Inhibit Input $\overline{INH}$					
Input voltage	$V_{\overline{INH}}$	-40	45	V	–
Sense Input SI					
Input voltage	V_{SI}	-0.3	45	V	–
Input current	I_{SI}	1	1	mA	–
Reset Threshold RADJ					
Voltage	V_{RE}	-0.3	7	V	–
Current	I_{RE}	-10	10	mA	–
Reset Delay D					
Voltage	V_D	-0.3	7	V	–
Reset Output RO					
Voltage	V_R	-0.3	7	V	–
Sense Output SO					
Voltage	V_{SO}	-0.3	7	V	–
5-V Output Q					
Output voltage	V_Q	-0.3	7	V	–
Output current	I_Q	-5	–	mA	–
Temperature					
Junction temperature	T_j	–	150	°C	–
Storage temperature	T_{Stg}	-50	150	°C	–
Operating Range					
Input voltage	V_I	4.5	45	V	–
Junction temperature	T_j	-40	150	°C	–

Table 3 Absolute Maximum Ratings (cont'd)

T_j = -40 to 150 °C

Parameter	Symbol	Limit Values		Unit	Notes
		Min.	Max.		
Thermal Data					
Junction-ambient	R_{thja}	– –	200 70	K/W K/W	P-DSO-8-3 P-DSO-14-8
Junction-pin	R_{thjp}	– –	60 30	K/W K/W	P-DSO-8-3 P-DSO-14-8[1)]

1) Measured to pin 4.

Note: Stresses above those listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
In the operating range, the functions given in the circuit description are fulfilled.

Table 4 Characteristics

V_I = 13.5 V; T_j = -40 °C < T_j < 150 °C

Parameter	Symbol	Limit Values			Unit	Measuring Condition
		Min.	Typ.	Max.		
Output voltage	V_Q	4.90	5.00	5.10	V	1 mA ≤ I_Q ≤ 100 mA; 6 V ≤ V_I ≤ 16 V
Output voltage	V_Q	4.85	5.00	5.15	V	I_Q ≤ 150 mA; 6 V ≤ V_I ≤ 16 V
Current limit	I_Q	250	400	500	mA	–
Current consumption; $I_q = I_I - I_Q$	I_q	–	65	105	µA	Inhibit ON; I_Q ≤ 1 mA, T_j < 85 °C
Current consumption; $I_q = I_I - I_Q$	I_q	–	65	100	µA	Inhibit ON; I_Q ≤ 1 mA, T_j = 25 °C
Current consumption; $I_q = I_I - I_Q$	I_q	–	170	500	µA	Inhibit ON; I_Q = 10 mA
Current consumption; $I_q = I_I - I_Q$	I_q	–	0.7	2	mA	Inhibit ON; I_Q = 50 mA
Current consumption; $I_q = I_I - I_Q$	I_q	–	–	1	µA	$V_{\overline{INH}}$ = 0 V; T_j = 25 °C
Drop voltage	V_{dr}	–	0.22	0.5	V	I_Q = 100 mA[1)]
Load regulation	ΔV_Q	–	5	30	mV	I_Q = 1 mA to 100 mA
Line regulation	ΔV_Q	–	10	25	mV	V_I = 6 V to 28 V; I_Q = 1 mA
Power Supply Ripple Rejection	$PSRR$	–	66	–	dB	f_r = 100 Hz; V_r = 1 Vpp; I_Q = 100 mA
Inhibit (TLE 4299 GM only)						
Inhibit OFF voltage range	$V_{\overline{INH}\ OFF}$	–	–	0.8	V	TLE 4299 GM; V_Q off
Inhibit ON voltage range	$V_{\overline{INH}\ ON}$	3.5	–	–	V	TLE 4299 GM; V_Q on
High input current	$I_{\overline{INH}\ ON}$	–	3	5	µA	TLE 4299 GM; $V_{\overline{INH}}$ = 5 V
Low input current	$I_{\overline{INH}\ OFF}$	–	0.5	2	µA	TLE 4299 GM; $V_{\overline{INH}}$ = 0 V

Table 4 Characteristics (cont'd)

V_I = 13.5 V; T_j = -40 °C < T_j < 150 °C

Parameter	Symbol	Limit Values			Unit	Measuring Condition
		Min.	Typ.	Max.		
Reset Generator						
Switching threshold	V_{rt}	4.50	4.60	4.80	V	–
Reset pull-up	R_{RO}	10	20	40	kΩ	–
Reset low voltage	V_R	–	0.17	0.40	V	V_Q < 4.5 V; internal R_{RO}; I_R = 1 mA
External reset pull-up	$V_{R\ ext}$	5.6	–	–	kΩ	Pull-up resistor to Q
Delay switching threshold	V_{DT}	1.5	1.85	2.2	V	–
Switching threshold	V_{ST}	0.35	0.50	0.60	V	–
Reset delay low voltage	V_D	–	–	0.1	V	V_Q < V_{RT}
Charge current	I_{ch}	4.0	8.0	12.0	µA	V_D = 1 V
Reset delay time	t_d	17	28	35	ms	C_D = 100 nF
Reset reaction time	t_{rr}	0.5	1.2	3.0	µs	C_D = 100 nF
Reset adjust switching threshold	$V_{RADJ\ TH}$	1.26	1.36	1.44	V	V_Q > 3.5 V
Input Voltage Sense						
Sense threshold high	$V_{SI\ high}$	1.34	1.45	1.54	V	–
Sense threshold low	$V_{SI\ low}$	1.26	1.36	1.44	V	–
Sense input switching hysteresis	$V_{SI\ HYST}$	50	90	130	mV	$V_{SI\ HYST}$ = $V_{SI\ high}$ - $V_{SI\ low}$
Sense output low voltage	$V_{SO\ low}$	–	0.1	0.4	V	V_{SI} < 1.20 V; V_i > 4.2 V; I_{SO} = 0
External SO pull-up resistor	$R_{SO\ ext}$	5.6	–	–	kΩ	–
Sense pull-up	R_{SO}	10	20	40	kΩ	–
Sense input current	I_{SI}	-1	0.1	1	µA	–
Sense high reaction time	$t_{pd\ SO\ LH}$	–	2.4	2.9	µs	–
Sense low reaction time	$t_{pd\ SO\ HL}$	–	1.7	2.1	µs	–

1) Drop voltage = V_I - V_Q (measured when the output voltage has dropped 100 mV from the nominal value obtained at 13.5 V input.)

Note: The listed characteristics are ensured over the operating range of the integrated circuit. Typical characteristics specify mean values expected over the production spread. If not otherwise specified, typical characteristics apply at T_A = 25 °C and the given supply voltage.

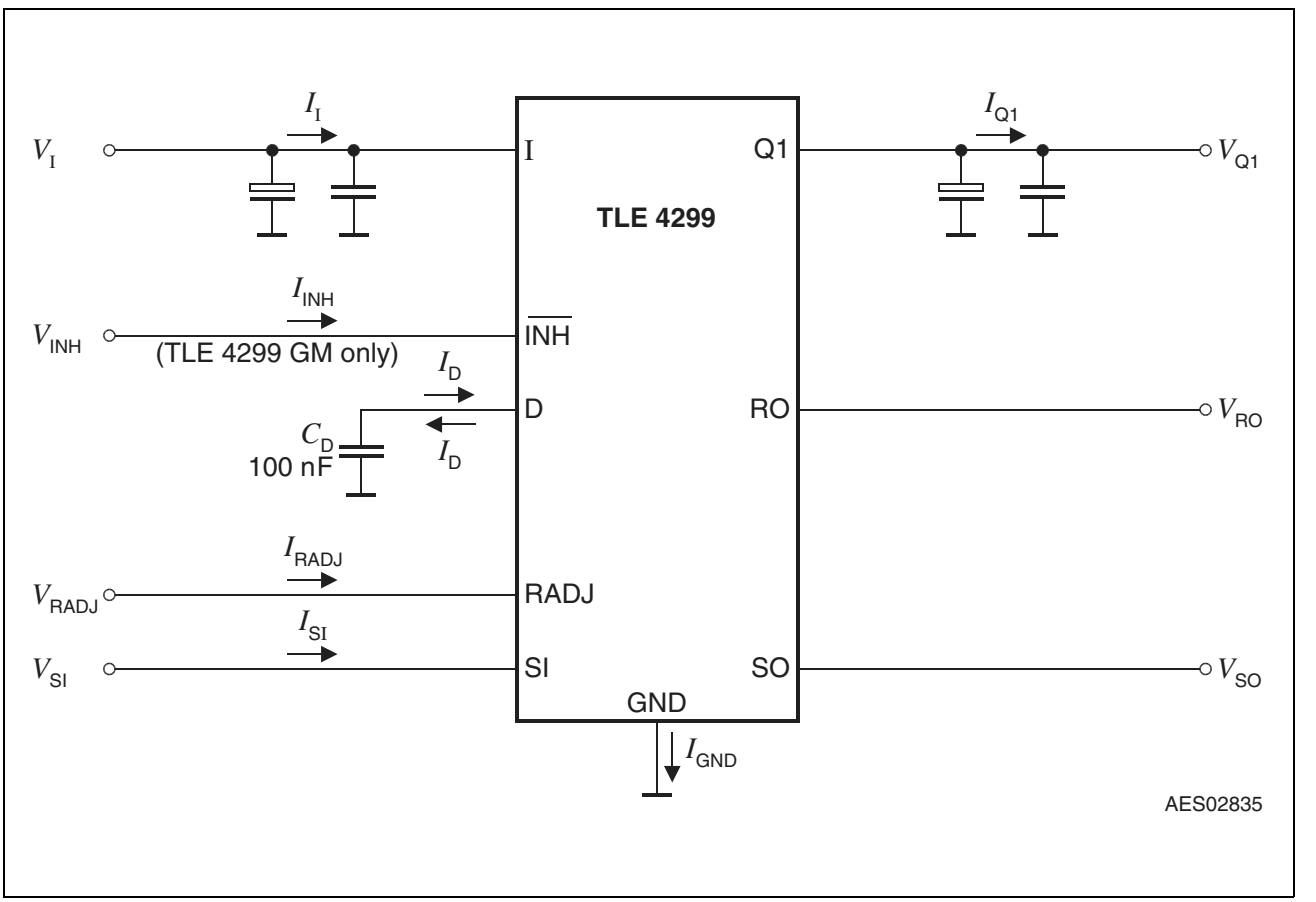


Figure 5 Measurement Circuit

Application Information

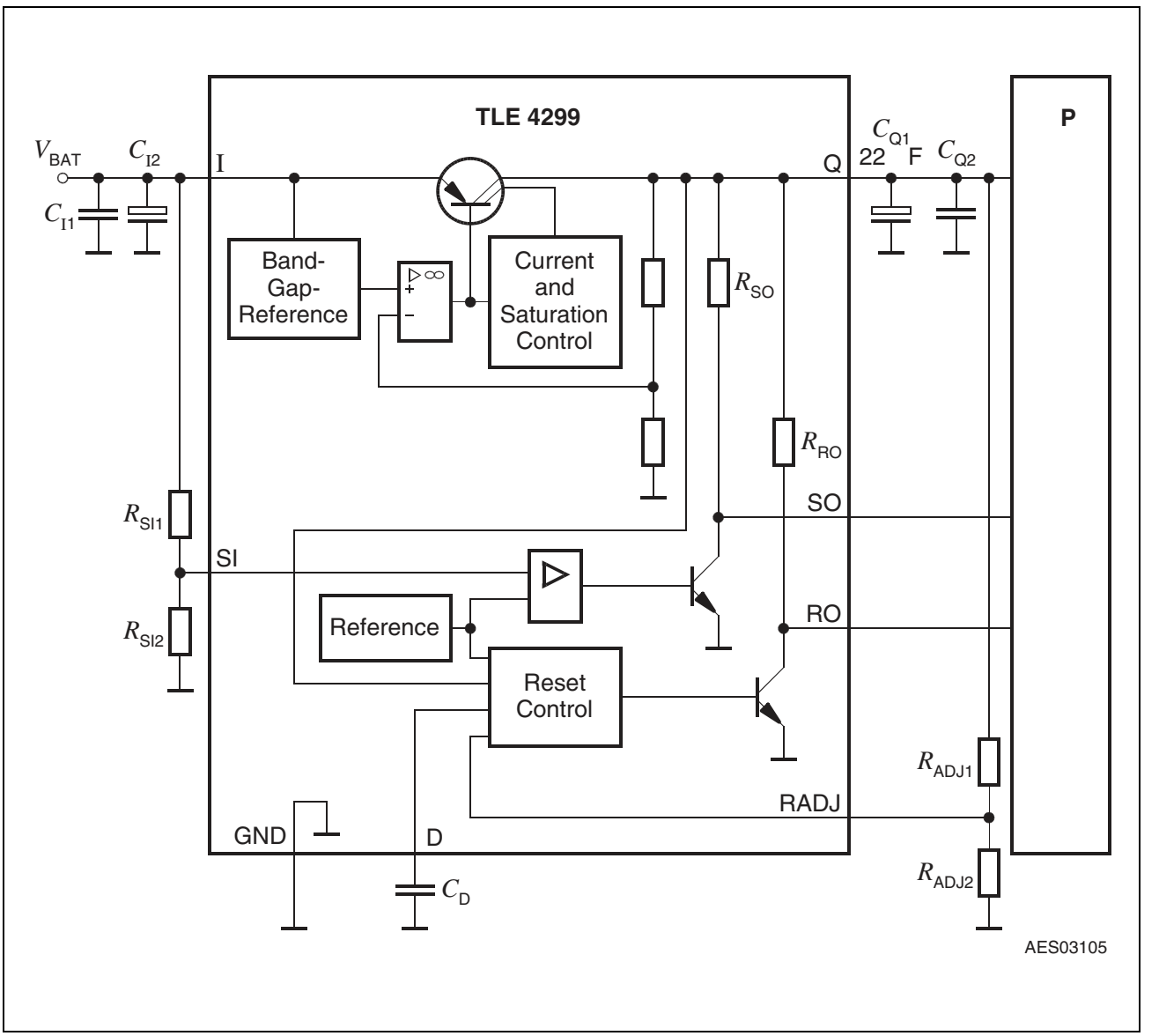


Figure 6 Application Diagram TLE 4299 G

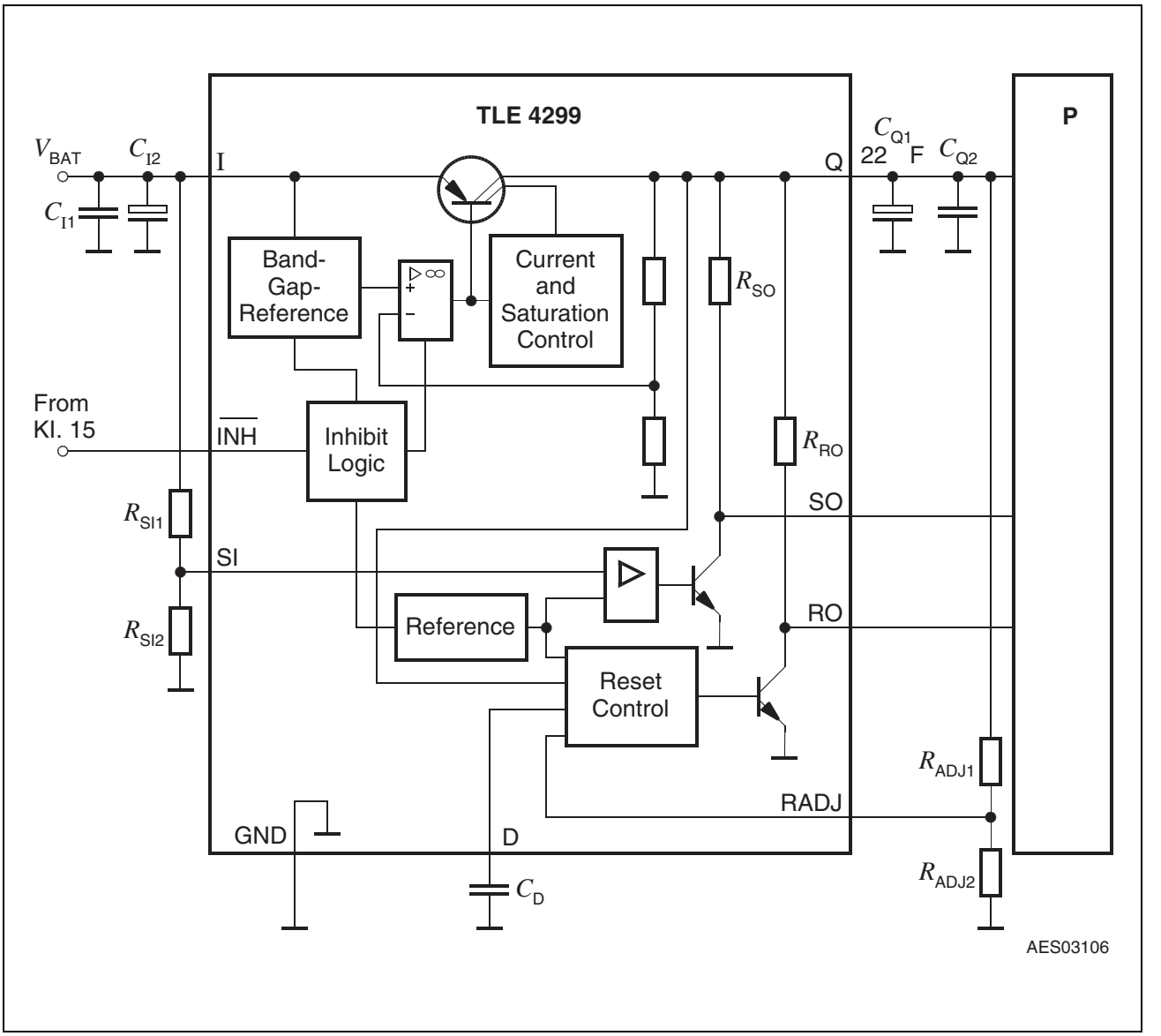


Figure 7 Application Diagram with Inhibit Function

The TLE 4299 supplies a regulated 5 V output voltage with an accuracy of 2% from an input voltage between 5.5 V and 45 V in the temperature range of T_j = -40 to 150 °C.

The device is capable to supply 150 mA. For protection at high input voltage above 25 V, the output current is reduced (SOA protection).

An input capacitor is necessary for compensating line influences and to limit steep input edges. A resistor of approx. 1 Ω in series with C_I, can damp the LC of the input inductivity and the input capacitor.

The voltage regulator requires for stability an output capacitor C_Q of at least 22 µF with an ESR below 5 Ω.

Reset

The power on reset feature is necessary for a defined start of the microprocessor when switching on the application. For the reset delay time after the output voltage of the regulator is above the reset threshold, the reset signal is set High again. The reset delay time is defined by the reset delay capacitor C_D at pin D.

The under-voltage reset circuitry supervises the output voltage. In case V_Q decreases below the reset threshold the reset output is set LOW after the reset reaction time. The reset LOW signal is generated down to an output voltage V_Q to 1 V. Both the reset reaction time and the reset delay time is defined by the capacitor value.

The power on reset delay time is defined by the charging time of an external delay capacitor C_D.

$$C_D = (t_d \times I_D) / \Delta V \quad (1)$$

Definitions:

- C_D = reset delay capacitor
- t_d = reset delay time
- $\Delta V = V_{UD}$, typical 1.8 V for power up reset
- $\Delta V = V_{UD} - V_{LD}$, typical 1.35 V for undervoltage reset
- I_D = charge current, typical 6.5 µA

For a delay capacitor C_D = 100 nF the typical power on reset delay time is 28 ms.

The reset reaction time t_{RR} is the time it takes the voltage regulator to set reset output LOW after the output voltage has dropped below the reset threshold. It is typically 1 µs for delay capacitor of 100 nF. For other values for C_D the reaction time can be estimated using the following equation:

$$t_{RR} = 10 \text{ ns / nF} \times C_D \quad (2)$$

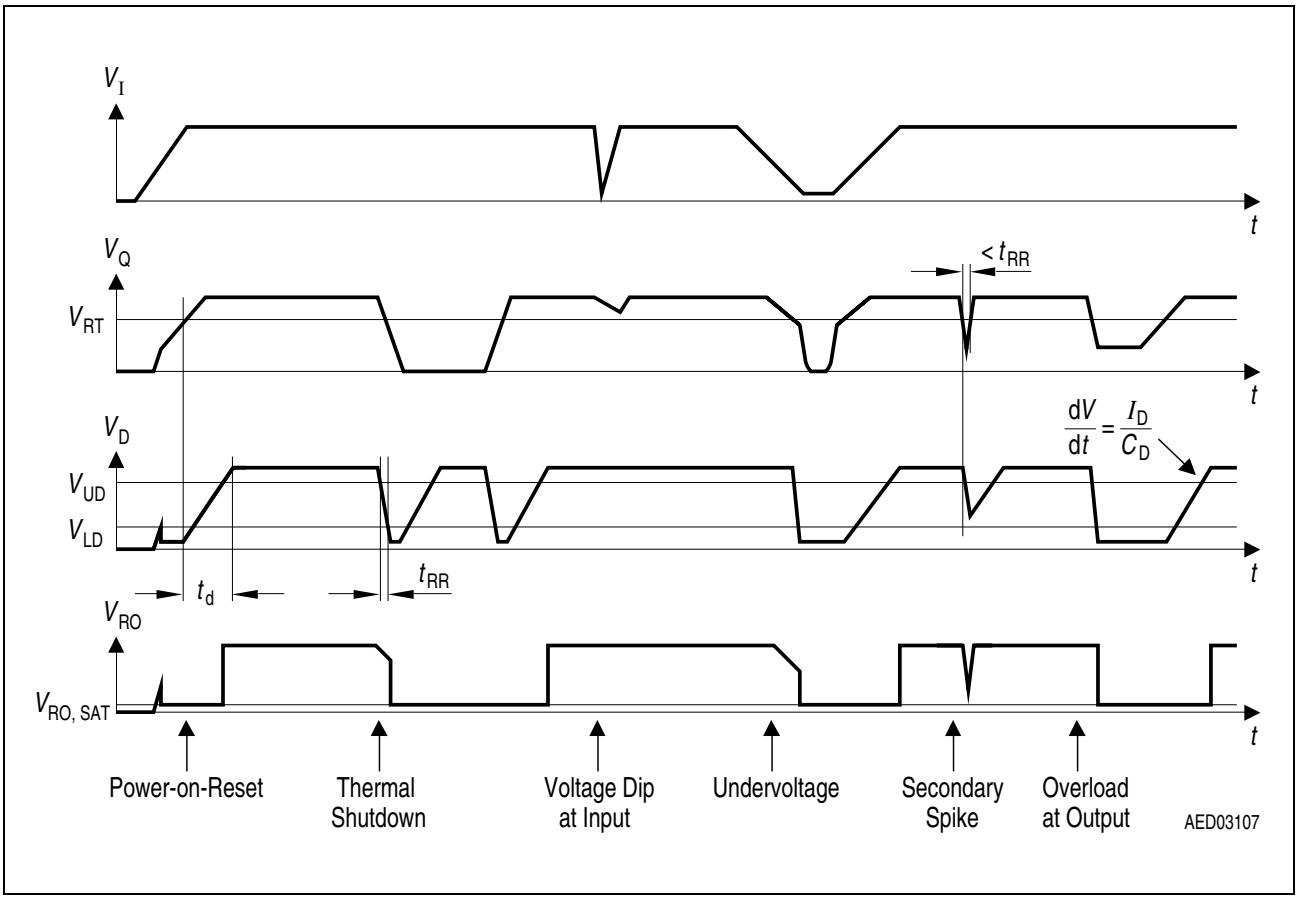


Figure 8 Reset Timing Diagram

The reset output is an open collector output with a pull-up resistor of typical 20 kΩ to Q. An external pull-up can be added with a resistor value of at least 5.6 kΩ.

In addition the reset switching threshold can be adjusted by an external voltage divider. The feature is useful for microprocessors which guarantee safe operation down to voltages below the internally set reset threshold of 4.65 V typical.

If the internal used reset threshold of typical 4.65 V is used, the pin RADJ has to be connected to GND.

If a lower reset threshold is required by the system, a voltage divider defines the reset threshold V_{Rth} between 3.5 V and 4.60 V:

$$V_{Rth} = V_{RADJ\ TH} \times (R_{ADJ1} + R_{ADJ2}) / R_{ADJ2} \quad (3)$$

$V_{RADJ\ TH}$ is typical 1.36 V.

Early Warning

The early warning function compares a voltage defined by the user to an internal reference voltage. Therefore the supervised voltage has to be scaled down by an

external voltage divider in order to compare it to the internal sense threshold of typical 1.35 V. The sense output pin is set low, when the voltage at SI falls below this threshold.

A typical example where the circuit can be used is to supervise the input voltage V_I to give the microcontroller a prewarning of low battery condition.

Calculation to the voltage divider can be easily done since the sense input current can be neglected.

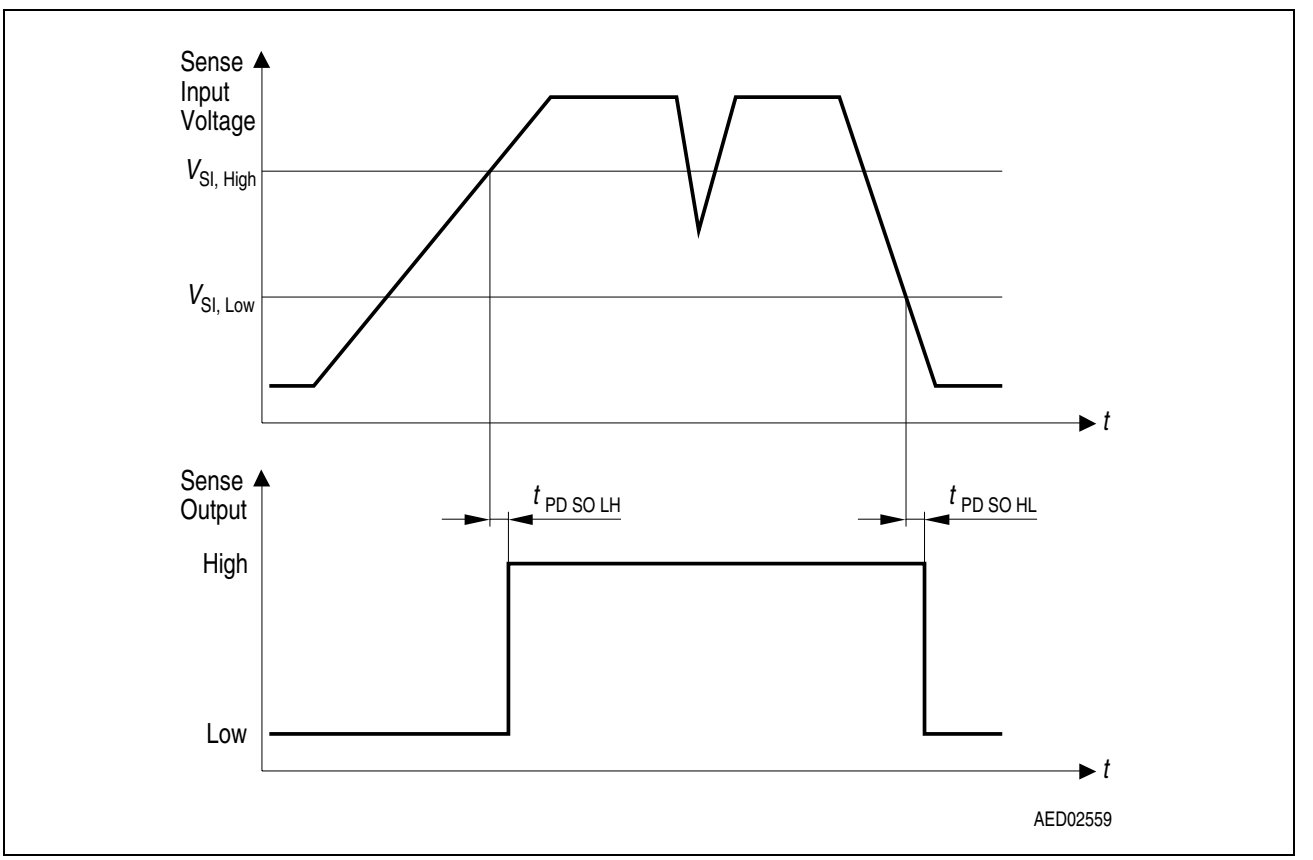


Figure 9 Sense Timing Diagram

$$V_{thHL} = (R_{SI1} + R_{SI2})/R_{SI2} \times V_{SI\ low} \quad (4)$$

$$V_{thLH} = (R_{SI1} + R_{SI2})/R_{SI2} \times V_{SI\ high} \quad (5)$$

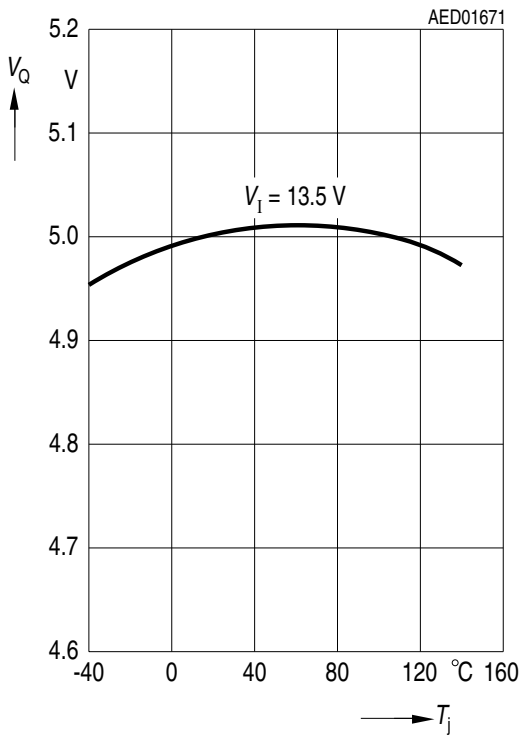
The sense in comparator uses a hysteresis of typical 100 mV. This hysteresis of the supervised threshold is multiplied by the resistor dividers amplification $(R_{SI1} + R_{SI2})/R_{SI1}$.

The sense in comparator can also be used for receiving data with a threshold of typical 1.35 V and a hysteresis of 100 mV. Of course also the data signal can be scaled down with a resistive divider as shown above. With a typical delay time of 2.4 µs for positive transitions and 1.7 µs for negative transitions receiving data of up to 100 kBaud are possible.

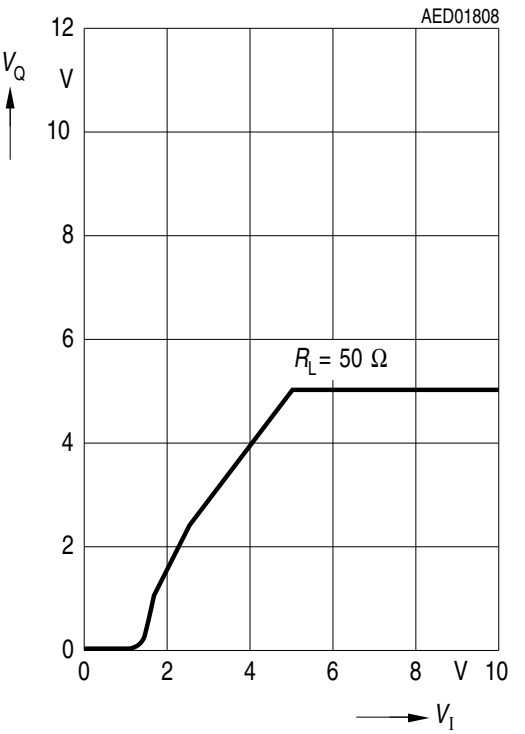
The sense output is an open collector output with a pull-up resistor of typical 20 kΩ to Q. An external pull-up can be added with a resistor value of at least 5.6 kΩ.

Typical Performance Characteristics

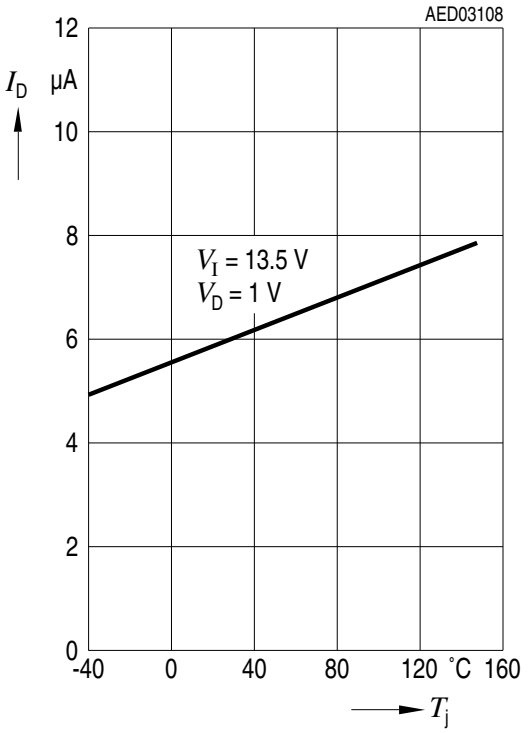
Output Voltage V_Q versus Temperature T_j



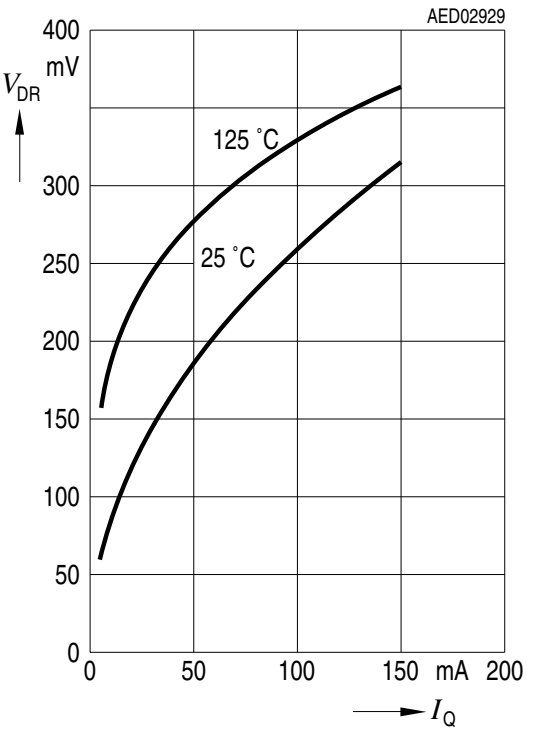
Output Voltage V_Q versus Input Voltage V_I



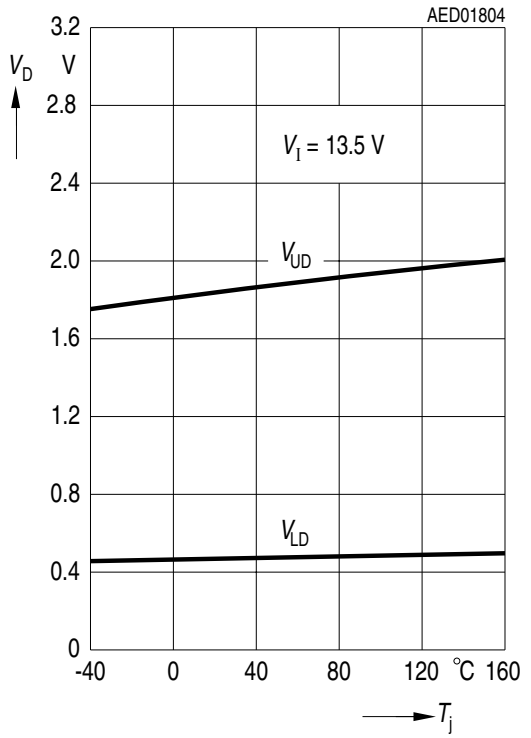
Charge Current I_{ch} versus Temperature T_j



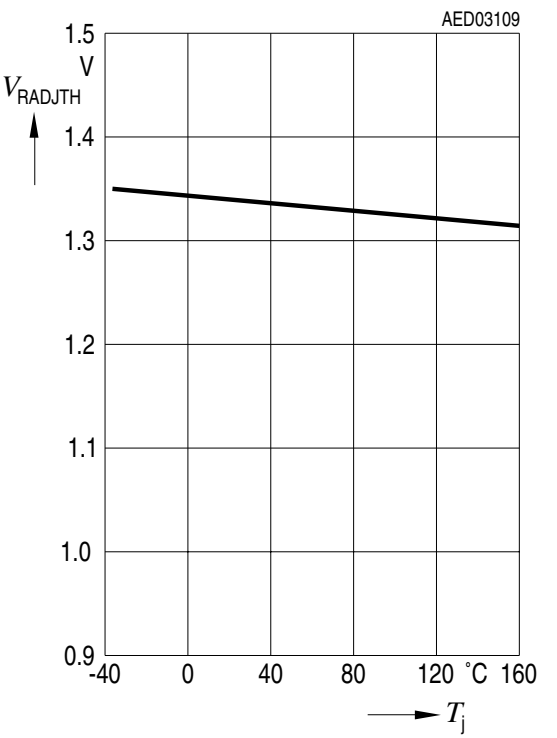
Drop Voltage V_{dr} versus Output Current I_Q



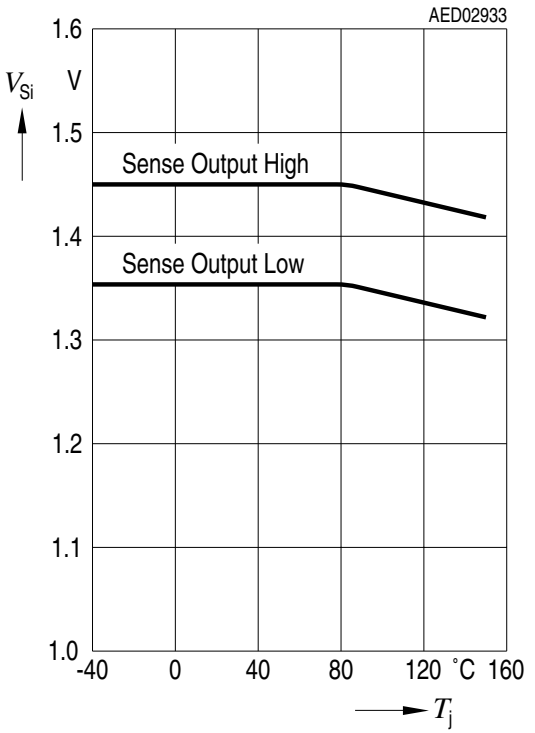
Switching Voltage V_{dt} and V_{st} versus Temperature T_j



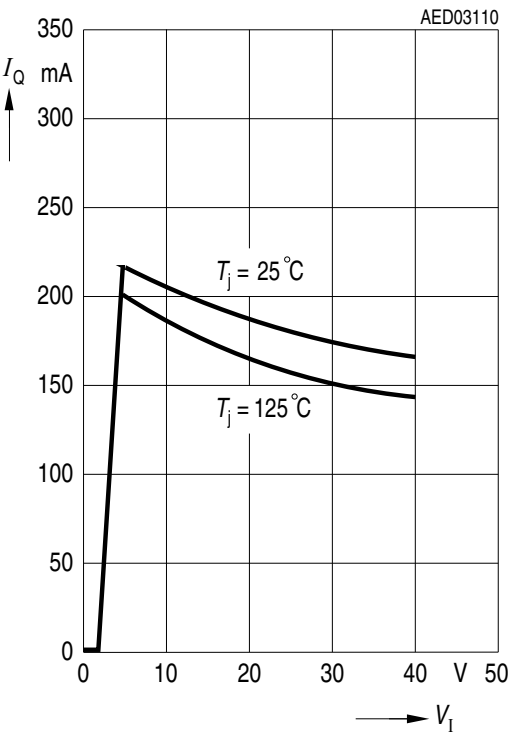
Reset Adjust Switching Threshold V_{RADJTH} versus Temperature T_j



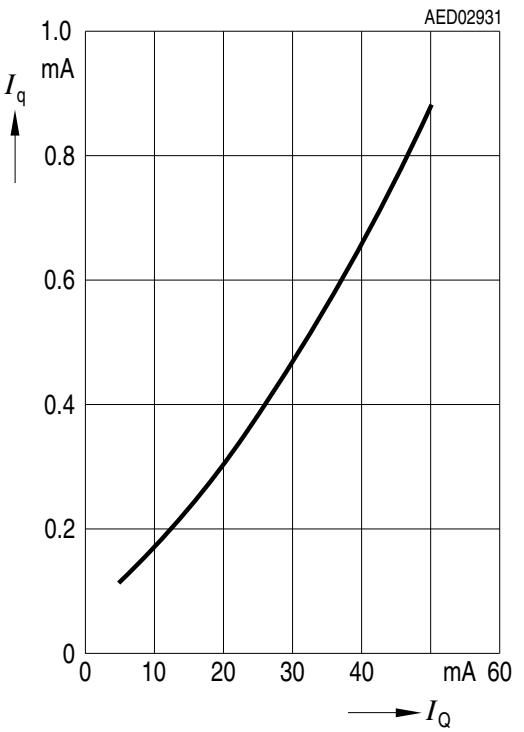
Sense Threshold V_{si} versus Temperature T_j



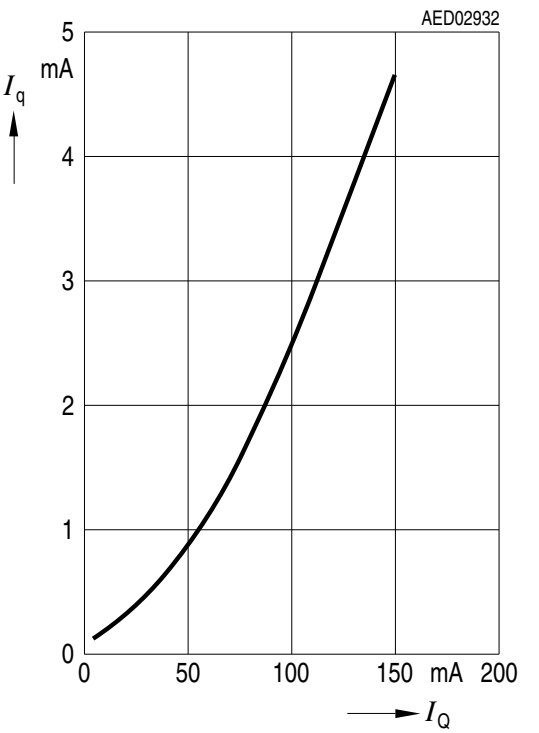
Output Current Limit I_Q versus Input Voltage V_I



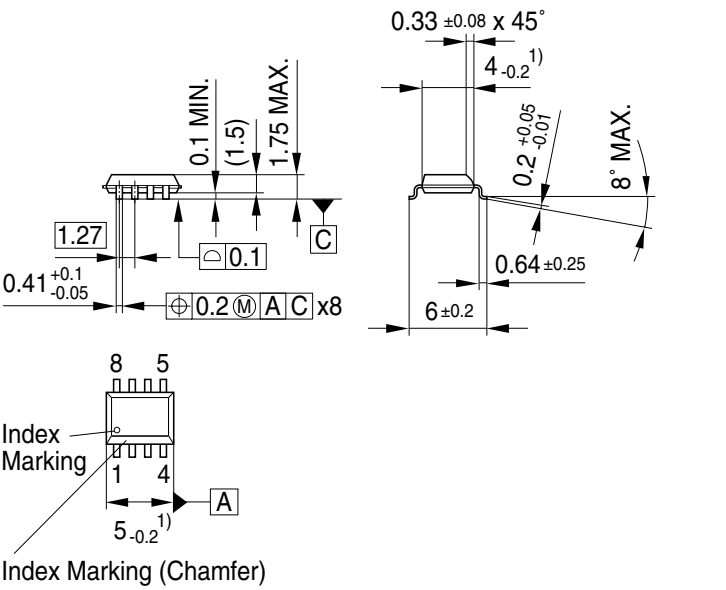
Current Consumption I_q versus Output Current I_Q



Current Consumption I_q versus Output Current I_Q



Package Outlines



1) Does not include plastic or metal protrusion of 0.15 max. per side

GPS09032

Figure 10 **P-DSO-8-3** (Plastic Dual Small Outline)

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SMD = Surface Mounted Device

Dimensions in mm

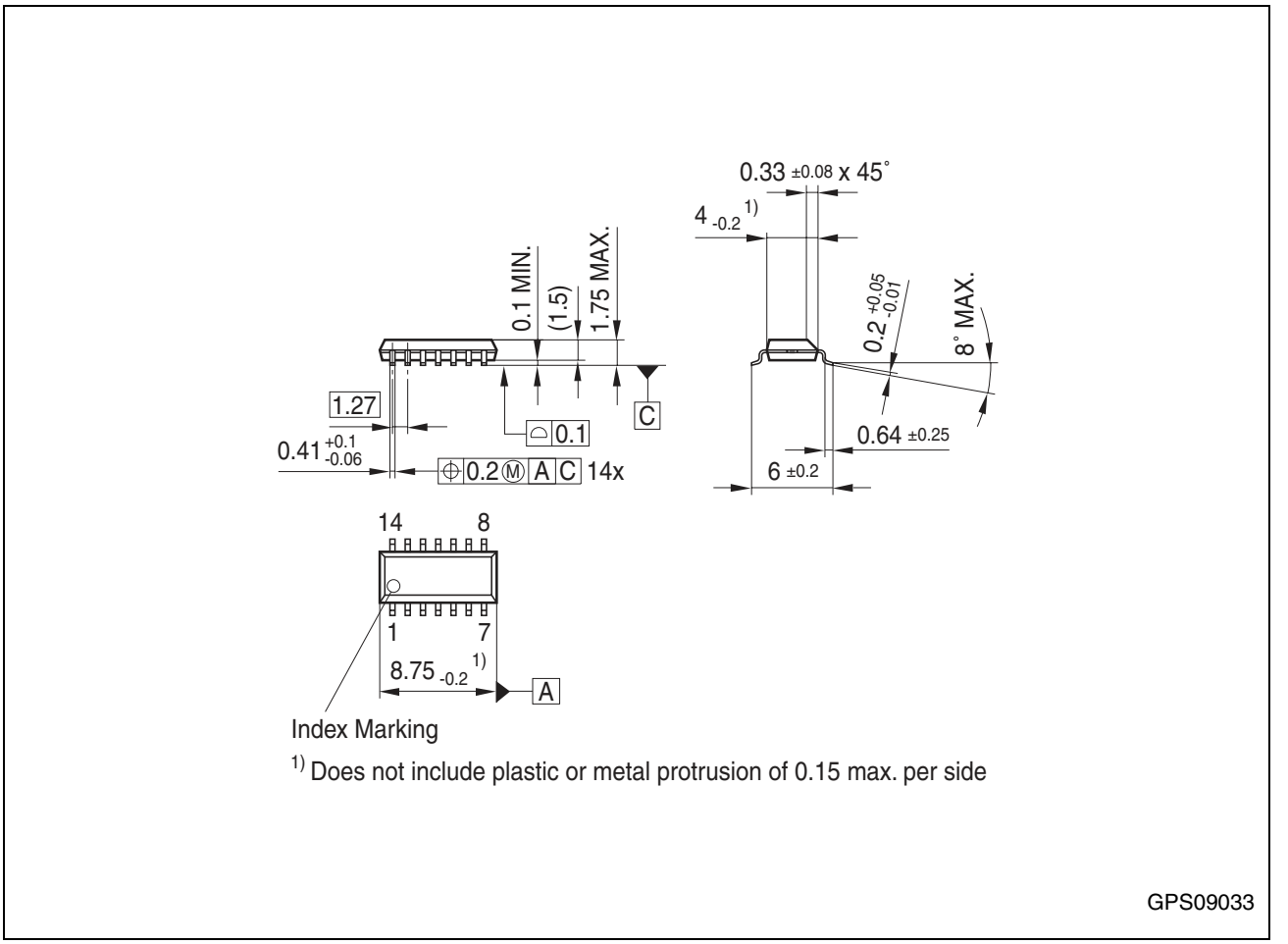

Figure 11 **P-DSO-14-8** (Plastic Dual Small Outline)

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SMD = Surface Mounted Device

Dimensions in mm

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Information

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